

DATA SHEET

**ELECTROSTATIC DISCHARGE
PROTECTION DEVICES**

INDUSTRIAL / CONSUMER

UAD8C05L01-R0.4

RoHS compliant & Halogen free



Product specification— March 27, 2021 V.2



ElectroStatic Discharged Protection Devices (ESD) Data Sheet

Description

The UAD8C05L01-R0.4 includes back-to-back TVS diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharge (ESD). This robust diodes can safely absorb repetitive ESD strikes up to the maximum level specified in the IEC61000-4-2 international standard without performance degradation.

The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.



Contact : ±20kV
Air : ±20kV

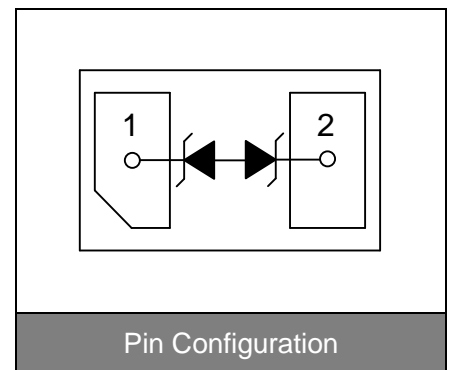


Features

- IEC61000-4-2 ESD 20KV Air, 20KV contact compliance
- SOD882 surface mount package
- Working voltage: 5V
- Low leakage current
- Low operating and clamping voltages
- Lead Free/RoHS compliant
- Flammability rating UL 94V-0
- Meets MSL level 1, per J-STD-020
- Marking: B1

Applications

- USB 3.0/USB 2.0
- MHL/MIPI/MDDI
- HDMI, Video Port, eSATA
- Set Top Boxes, Game Consoles
- Smart Phones
- External Storage
- Ultrabooks, Notebooks
- Tablets, eReaders



Maximum Ratings

| Rating | Symbol | Value | Unit |
|---------------------------------------|----------------|----------|------|
| ESD voltage (Contact discharge) | V_{ESD} | ± 20 | kV |
| ESD voltage (Air discharge) | | ± 20 | |
| Storage & operating temperature range | T_{STG}, T_J | -55~+150 | °C |

Electrical Characteristics (T_J=25°C)

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--------------------------------|------------------|----------------------|------|------|------|------|
| Reverse stand-off voltage | V _{RWM} | | | | 5.0 | V |
| Reverse breakdown voltage | V _{BR} | I _{BR} =1mA | 6.0 | | | V |
| Reverse leakage current | I _R | V _R =5V | | | 1.0 | μA |
| Clamping voltage (tp=8/20μs) | V _C | I _{PP} =3A | | 18 | | V |
| Peak Pulse Current (tp=8/20μs) | I _{PP} | | | | 3 | A |
| Off state junction capacitance | C _J | 0Vdc,f=1MHz | | 0.3 | 0.4 | pF |

Typical Characteristics Curves

Figure 1. Pulse Waveform

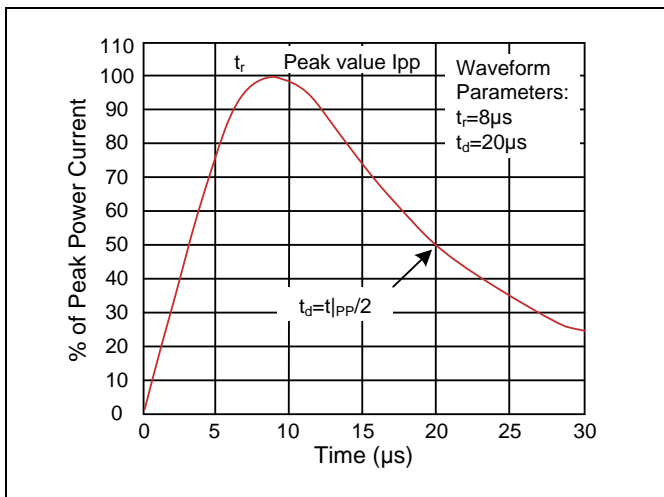


Figure 2. Clamping Voltage vs. Peak Pulse Current

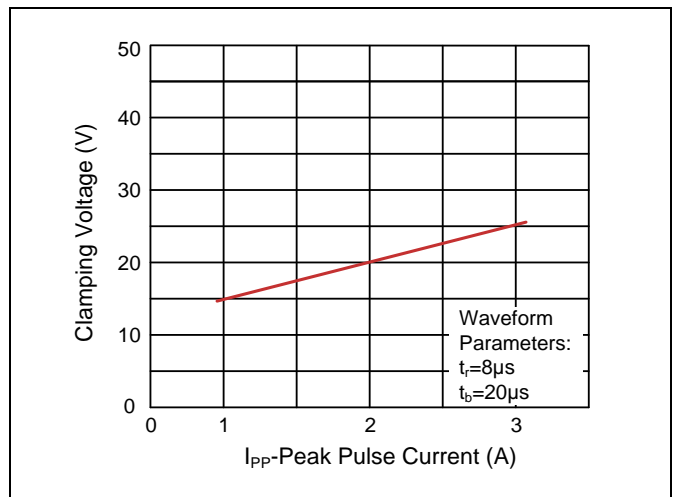


Figure 3. Capacitance vs. Reverse Voltage

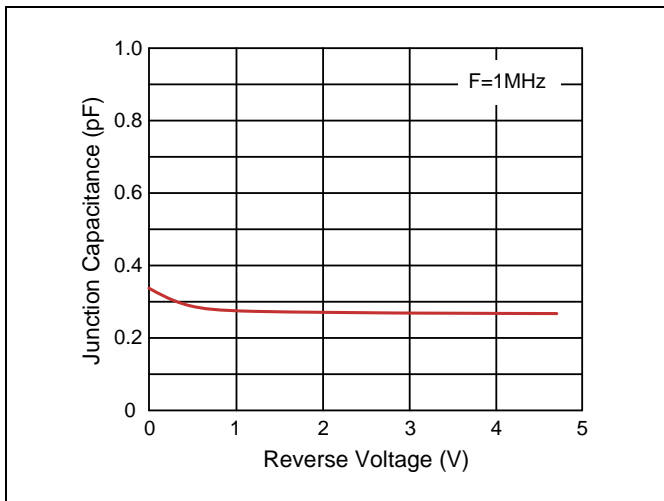
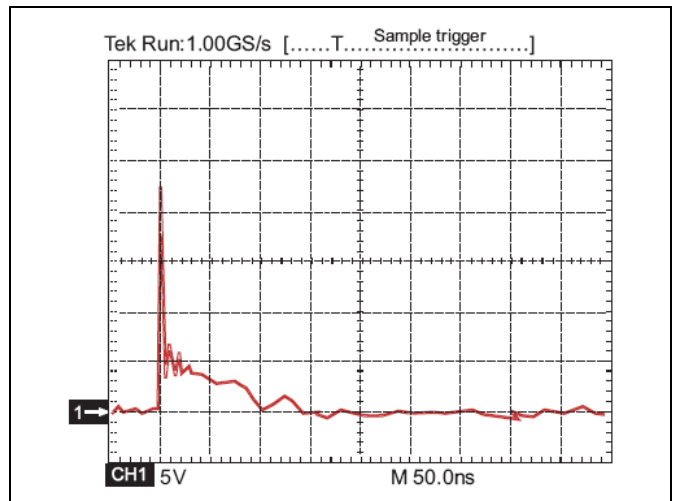
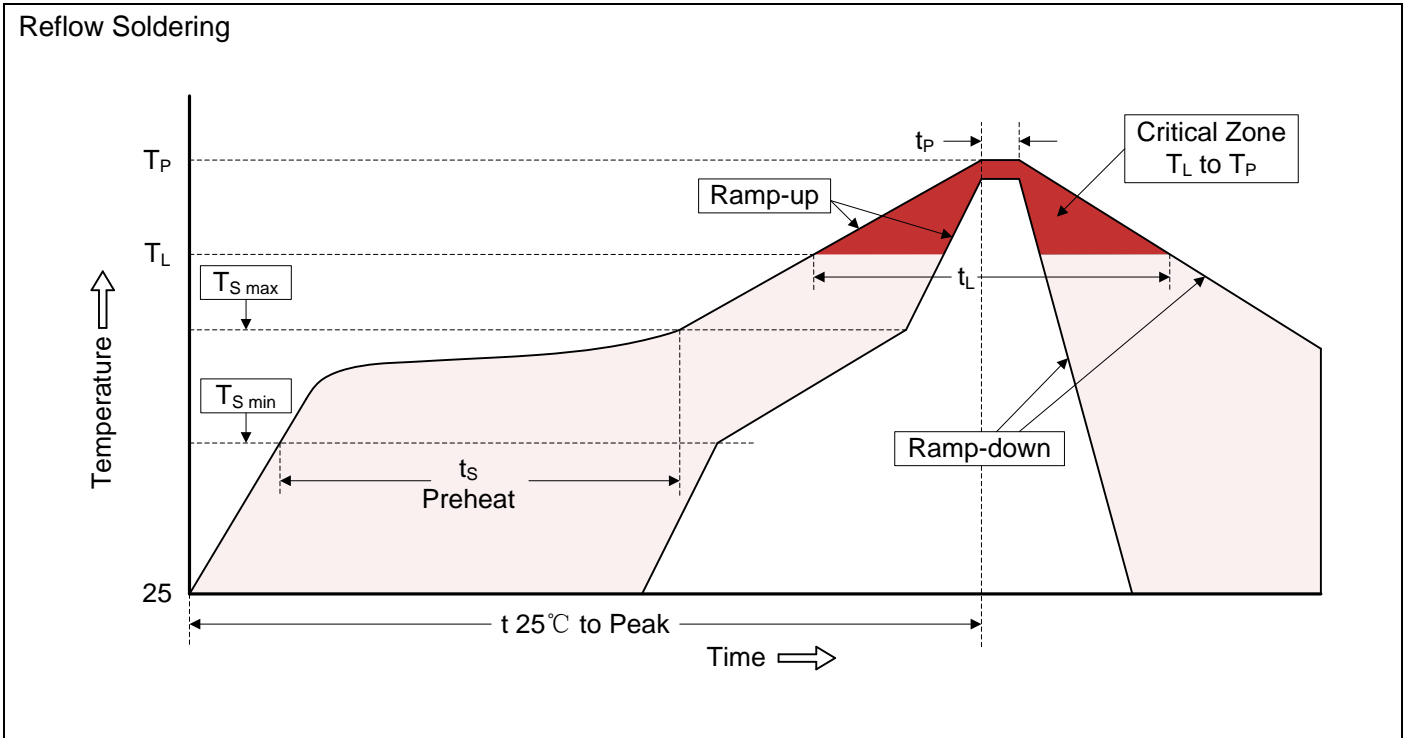


Figure 4. ESD Clamping (8kV Contact IEC61000-4-2)



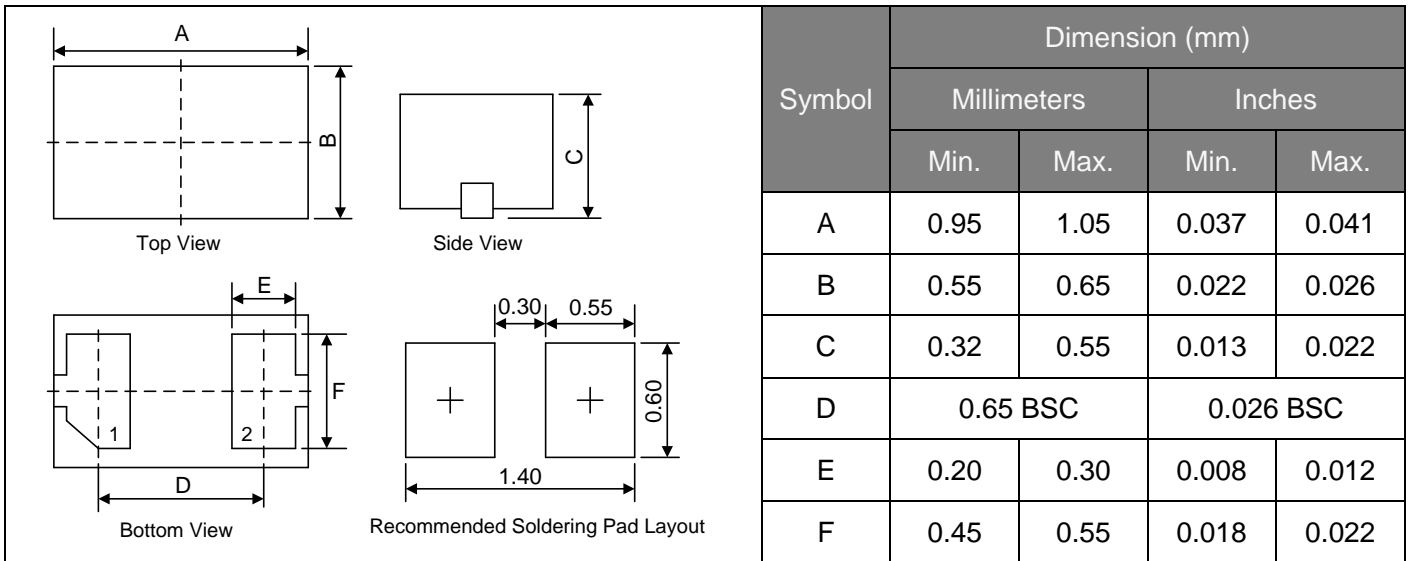
Recommended Soldering Conditions



Recommended Conditions

| Profile Feature | Pb-Free Assembly |
|---|----------------------------------|
| Average ramp-up rate (T_L to T_P) | 3°C/second max. |
| Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s) | 150°C 200°C 60-180 seconds |
| $T_{S\ max}$ to T_L -Ramp-up Rate | 3°C/second max. |
| Time maintained above: -Temperature (T_L) -Time (t_L) | 217°C 60-150 seconds |
| Peak Temperature (T_P) | 260°C |
| Time within 5°C of actual Peak Temperature (t_P) | 20-40 seconds |
| Ramp-down Rate | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |

Dimensions (SOD-882)



Packaging

